

Super Barrier Rectifier

Using state-of-the-art SBR IC process technology, the following features are made possible in a single device:

Major ratings and characteristics

Characteristics	Values	Units
I _{F(AV)} Rectangular Waveform	1.0 *	A
V_{RRM}	40	V
V _F @1A, T _J =75°C	0.42	V, typ
T _J (operating/storage)	-65 to 125	°C

*Note: Device monuted on a glass epoxy board,

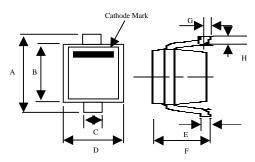
Board size: 50mm x 50m, Land size: 6mm x 6mm

ELECTRICAL:

- * Low Forward Voltage Drop
- * Low Reverse Leakage
- * Reliable High Temperature Operation
- * Super Barrier Design
- * Softest, fast switching capability
- * 125°C Operating Junction Temperature

MECHANICAL:

* Molded Plastic SOD-323 package



	23		
Di	Min	Max	
A	2.30	2.70	
В	1.60	1.80	
С	0.25	0.40	
D	1.15	1.45	
Е	0.10	0.18	
F	0.85	1.05	
G	-	0.10	
Н	0.20	0.40	
All Dimensions in mm			

Maximum	Ratings	and	Electrical	l Characteristics
/ · o=0a				IN.

(at 25 C unless otherwise specified)						
	SYMBOL			UNITS		
DC Blocking Voltage Working Peak Reverse Voltage Peak Repetitive Reverse Voltage	V _{RM} V _{RWM} V _{RRM}	40		Volts		
Average Rectified Forward Current (Rated V _R - 20Khz Square Wave) - 50% duty cycle	I _O ⁽¹⁾	1		Amps		
Peak Forward Surge Current - 1/2 60hz	I _{FSM}	18		Amps		
Instantaneous Forward Voltage $I_F = 0.7A$; $T_J = 25^{\circ}C$ $I_F = 1A$; $T_J = 25^{\circ}C$ $I_F = 0.7A$; $T_J = 75^{\circ}C$	V _F	Typ 0.44 	Max 0.44 0.39	Volts		
Maximum Reverse Current at Rated V_{RM} $T_J = 25^{\circ}C$ $T_J = 75^{\circ}C$	I _R ⁽²⁾	Тур 	Max 0.2 2	mA mA		
Operating and Storage Junction Temperature	T.	-65 to +125		°C		

⁽¹⁾ We recommend that the worst case current be no greater than 80% of the maximum rating of I $_{
m O}$

⁽²⁾ Pulse width < 300 uS, Duty cycle < 2%

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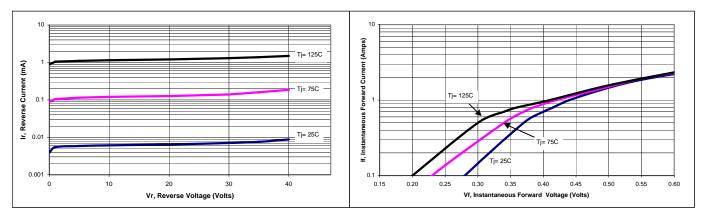


Figure 1: Typical Reverse Current

Figure 2: Typical Forward Voltage

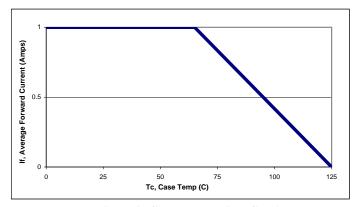
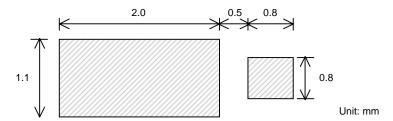


Figure 3: Current Derating, Case*

STANDARD SOLDERING PAD:



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^{*}Device mounted on a 50mm x 50mm glass epoxy board, 50% duty cycle